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Kind regards,

Team Nexperia



BAS56 High-speed double diode Rev. 3 – 29 June 2010

Product data sheet

# 1. Product profile

### 1.1 General description

Two high-speed switching diodes fabricated in planar technology, and encapsulated in a small SOT143B Surface-Mounted Device (SMD) plastic package. The diodes are not connected.

### **1.2 Features and benefits**

- High switching speed:  $t_{rr} \le 6$  ns
- Reverse voltage:  $V_R \le 60 V$
- Repetitive peak reverse voltage:  $V_{RRM} \le 60 \text{ V}$
- Repetitive peak forward current: I<sub>FRM</sub> ≤ 600 mA
- AEC-Q101 qualified
- Small SMD plastic package

### 1.3 Applications

High-speed switching in e.g. surface-mounted circuits

## 1.4 Quick reference data

### Table 1. Quick reference data

| Symbol          | Parameter             | Conditions   | Min        | Тур | Max | Unit |
|-----------------|-----------------------|--------------|------------|-----|-----|------|
| I <sub>F</sub>  | forward current       |              | [1][2] _   | -   | 200 | mA   |
| I <sub>R</sub>  | reverse current       | $V_R = 60 V$ | -          | -   | 100 | nA   |
| V <sub>R</sub>  | reverse voltage       |              | -          | -   | 60  | V    |
| t <sub>rr</sub> | reverse recovery time |              | <u>[3]</u> | -   | 6   | ns   |

[1] Single diode loaded.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB).

[3] When switched from I<sub>F</sub> = 400 mA to I<sub>R</sub> = 400 mA; R<sub>L</sub> = 100  $\Omega$ ; measured at I<sub>R</sub> = 40 mA.



High-speed double diode

#### **Pinning information** 2.

| Table 2. | Pinning           |                    |                |
|----------|-------------------|--------------------|----------------|
| Pin      | Description       | Simplified outline | Graphic symbol |
| 1        | cathode (diode 1) |                    |                |
| 2        | cathode (diode 2) |                    | 4 3            |
| 3        | anode (diode 2)   |                    |                |
| 4        | anode (diode 1)   |                    |                |

006aab100

#### **Ordering information** 3.

| Table 3. Orde | Ordering information |  |         |  |  |  |
|---------------|----------------------|--|---------|--|--|--|
| Type number   | Package              |  |         |  |  |  |
|               | Name                 | Description                              | Version |  |  |  |
| BAS56         | -                    | plastic surface-mounted package; 4 leads | SOT143B |  |  |  |

#### Marking 4.

| Marking code <sup>[1]</sup> |
|-----------------------------|
| *L5                         |
|                             |

[1] \* = -: made in Hong Kong \* = p: made in Hong Kong

- \* = t: made in Malaysia
- \* = W: made in China

# 5. Limiting values

| Symbol           | Parameter                           | Conditions               |            | Min | Max  | Unit |
|------------------|-------------------------------------|--------------------------|------------|-----|------|------|
| V <sub>RRM</sub> | repetitive peak reverse             |                          |            | -   | 60   | V    |
|                  | voltage                             |                          | [1]        | -   | 120  | V    |
| V <sub>R</sub>   | reverse voltage                     |                          |            | -   | 60   | V    |
|                  |                                     |                          | [1]        | -   | 120  | V    |
| l <sub>F</sub>   | forward current                     |                          | [2][3]     | -   | 200  | mA   |
|                  |                                     |                          | [2][4]     | -   | 150  | mA   |
|                  | repetitive peak forward             |                          | <u>[3]</u> | -   | 600  | mA   |
|                  | current                             |                          | [4]        | -   | 430  | mA   |
| I <sub>FSM</sub> | non-repetitive peak forward current | square wave              | <u>[5]</u> |     |      |      |
|                  |                                     | $t_p = 1 \ \mu s$        |            | -   | 9    | А    |
|                  |                                     | t <sub>p</sub> = 100 μs  |            | -   | 3    | А    |
|                  |                                     | t <sub>p</sub> = 10 ms   |            | -   | 1.7  | А    |
| P <sub>tot</sub> | total power dissipation             | T <sub>amb</sub> = 25 °C | [2]        | -   | 250  | mW   |
| Tj               | junction temperature                |                          |            | -   | 150  | °C   |
| T <sub>stg</sub> | storage temperature                 |                          |            | -65 | +150 | °C   |

[1] Series connection.

[2] Device mounted on an FR4 PCB.

[3] Single diode loaded.

[4] Double diode loaded.

[5]  $T_j = 25 \,^{\circ}C$  prior to surge.

# 6. Thermal characteristics

### Table 6.Thermal characteristics

| Symbol               | Parameter                                     | Conditions  | Min          | Тур | Max | Unit |
|----------------------|---|-------------|--------------|-----|-----|------|
| R <sub>th(j-a)</sub> | thermal resistance from junction to ambient   | in free air | <u>[1]</u> _ | -   | 500 | K/W  |
| R <sub>th(j-t)</sub> | thermal resistance from junction to tie-point |             | -            | -   | 360 | K/W  |

[1] Device mounted on an FR4 PCB.

# 7. Characteristics

| $T_j = 25 \ ^{\circ}C$ | unless otherwise specified | l.   |     |     |     |     |      |
|------------------------|----------------------------|--|-----|-----|-----|-----|------|
| Symbol                 | Parameter                  | Conditions   |     | Min | Тур | Max | Unit |
| V <sub>F</sub>         | forward voltage            | I <sub>F</sub> = 200 mA                                  | [1] | -   | -   | 1   | V    |
| l <sub>R</sub> ro      | reverse current            | V <sub>R</sub> = 60 V                                    |     | -   | -   | 100 | nA   |
|                        |                            | $V_R = 60 \text{ V}; \text{ T}_j = 150 ^{\circ}\text{C}$ |     | -   | -   | 100 | μA   |
|                        |                            | V <sub>R</sub> = 120 V                                   | [2] | -   | -   | 100 | nA   |
|                        |                            | $V_R$ = 120 V; $T_j$ = 150 °C                            | [2] | -   | -   | 100 | μA   |
| C <sub>d</sub>         | diode capacitance          | f = 1 MHz; V <sub>R</sub> = 0 V                          |     | -   | -   | 2.5 | pF   |
| t <sub>rr</sub>        | reverse recovery time      |  | [3] | -   | -   | 6   | ns   |
| $V_{FR}$               | forward recovery voltage   |  | [4] | -   | -   | 2   | V    |
|                        |                            |  | [5] | -   | -   | 1.5 | V    |

[1]  $T_{amb} = 25 \text{ °C}$ ; device has reached the thermal equilibrium when mounted on an FR4 PCB.

[2] Series connection.

[3] When switched from I<sub>F</sub> = 400 mA to I<sub>R</sub> = 400 mA; R<sub>L</sub> = 100  $\Omega$ ; measured at I<sub>R</sub> = 40 mA.

[4] When switched from  $I_F$  = 400 mA;  $t_r$  = 30 ns.

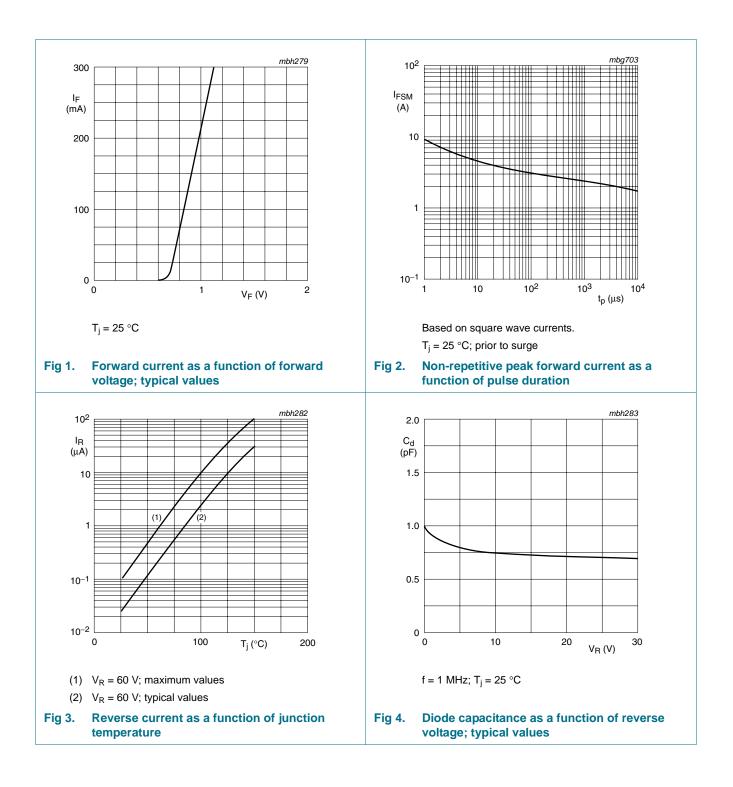
[5] When switched from  $I_F = 400 \text{ mA}$ ;  $t_r = 100 \text{ ns}$ .

\_\_\_\_\_

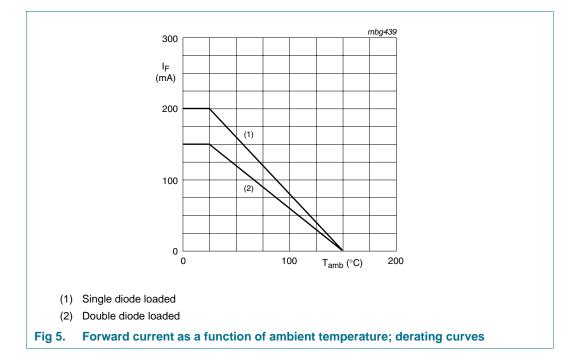
### **NXP Semiconductors**

### High-speed double diode

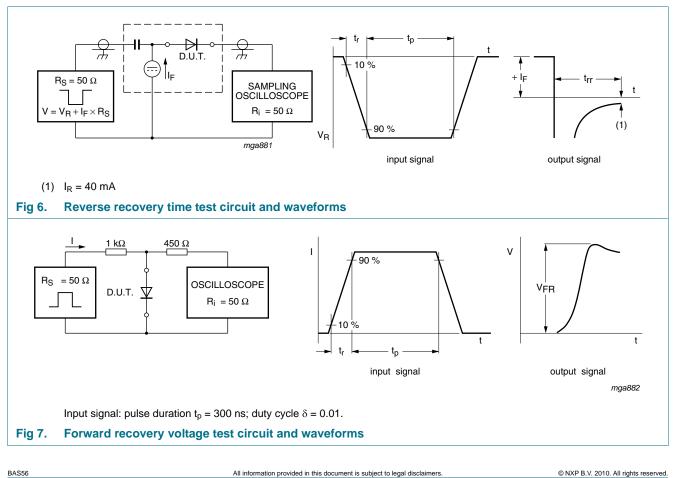
**BAS56** 



High-speed double diode



#### **Test information** 8.

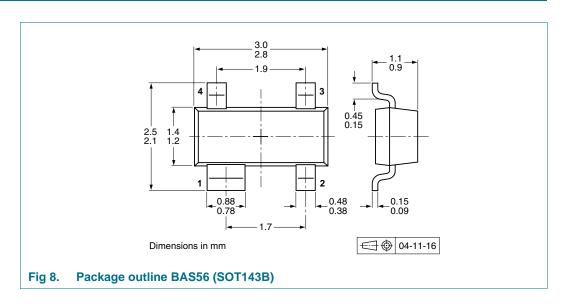


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### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

# 9. Package outline



# **10. Packing information**

### Table 8.Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

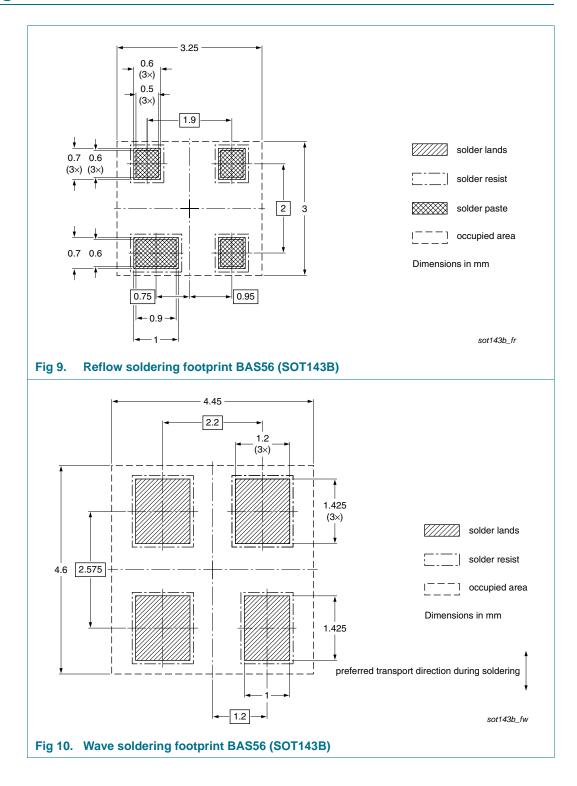
| Type number | Package | Description                    | Packing | Packing quantity |  |
|-------------|---------|--------------------------------|---------|------------------|--|
|             |         |                                | 3000    | 10000            |  |
| BAS56       | SOT143B | 4 mm pitch, 8 mm tape and reel | -215    | -235             |  |

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

High-speed double diode

**BAS56** 

# 11. Soldering



# **12. Revision history**

| Document ID    | Release date                                     | Data sheet status   | Change notice        | Supersedes       |  |  |  |
|----------------|--|---|----------------------|------------------|--|--|--|
| BAS56 v.3      | 20100629   | Product data sheet  | -                    | BAS56_2          |  |  |  |
| Modifications: |  | <ul> <li>The format of this data sheet has been redesigned to comply with the new identity<br/>guidelines of NXP Semiconductors.</li> </ul> |                      |                  |  |  |  |
|                | <ul> <li>Legal texts</li> </ul>                  | have been adapted to the r  | new company name whe | ere appropriate. |  |  |  |
|                | Section 1.1                                      | "General description": ame  | nded                 |                  |  |  |  |
|                | <ul> <li>Section 4 "Marking": updated</li> </ul> |   |                      |                  |  |  |  |
|                | Table 1 "Qu                                      | ick reference data": added  |                      |                  |  |  |  |
|                | Section 8 "                                      | <ul> <li>Section 8 "Test information": added</li> </ul>   |                      |                  |  |  |  |
|                | • Figure 8: su                                   | <ul> <li>Figure 8: superseded by minimized package outline drawing</li> </ul>   |                      |                  |  |  |  |
|                | Section 10                                       | "Packing information": adde   | ed                   |                  |  |  |  |
|                | Section 11                                       | <u>'Soldering"</u> : added  |                      |                  |  |  |  |
|                | Section 13                                       | "Legal information": update   | d                    |                  |  |  |  |
| BAS56_2        | 19960910   | Product specification   | -                    | BAS56_1          |  |  |  |
| BAS56 1        | 19960423   | Product specification   | -                    | -                |  |  |  |

# 13. Legal information

#### 13.1 Data sheet status

| Document status[1][2]          | Product status <sup>[3]</sup> | Definition  |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet   | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions"

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